

## ESD9N5BU

**1-Line, Bi-directional, Ultra-low Capacitance,  
Transient Voltage Suppressor**

<http://www.sh-willsemi.com>

### Descriptions

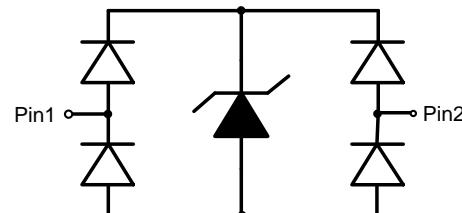
The ESD9N5BU is a transient voltage suppressors (TVS) which provide a very high level protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). It is designed to replace multiplayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

The ESD9N5BU was past ESD transient voltage up to  $\pm 12\text{kV}$  (contact) according to IEC61000-4-2 and withstand peak current up to 3A for 8/20 $\mu\text{s}$  pulse according to IEC61000-4-5.

The ESD9N5BU is available in DFN1006 package. Standard products are Pb-free and Halogen-free.



**DFN1006-2L (Bottom View)**



**Circuit Diagram**



\* = Month (A~Z)  
U = Device code  
**Marking (Top View)**

### Features

- Reverse stand-off voltage:  $\pm 5.0\text{V}$  max.
- Transient protection for each line according to IEC61000-4-2 (ESD) :  $\pm 12\text{kV}$  (contact discharge) :  $\pm 15\text{kV}$  (air discharge)
- IEC61000-4-4 (EFT) : 40A (5/50ns)
- IEC61000-4-5 (surge) : 3A (8/20 $\mu\text{s}$ )
- Ultra-low capacitance
- Low clamping voltage
- Low leakage current
- Small package

### Applications

- Mobile phone
- PAD
- Notebook
- STB
- LCD TV
- Digital camera
- Other electronics equipments

### Order information

Device	Package	Shipping
ESD9N5BU-2/TR	DFN1006-2L	10000/Tape&Reel

## Absolute maximum ratings

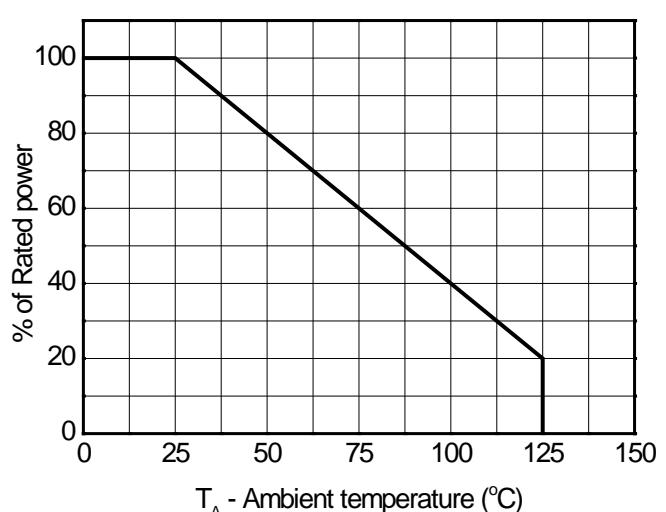
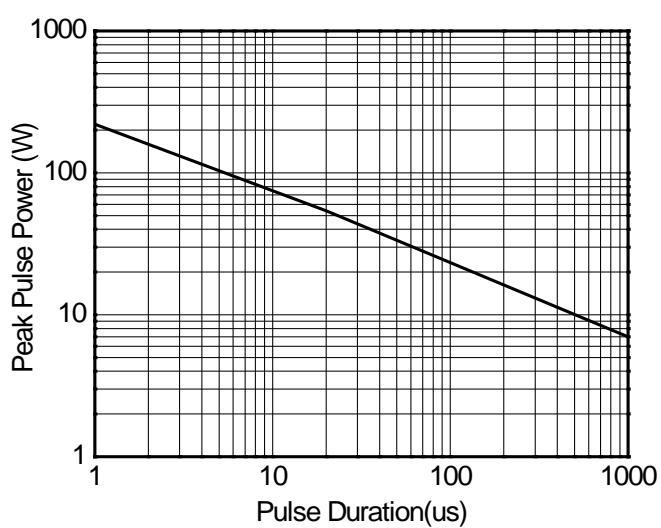
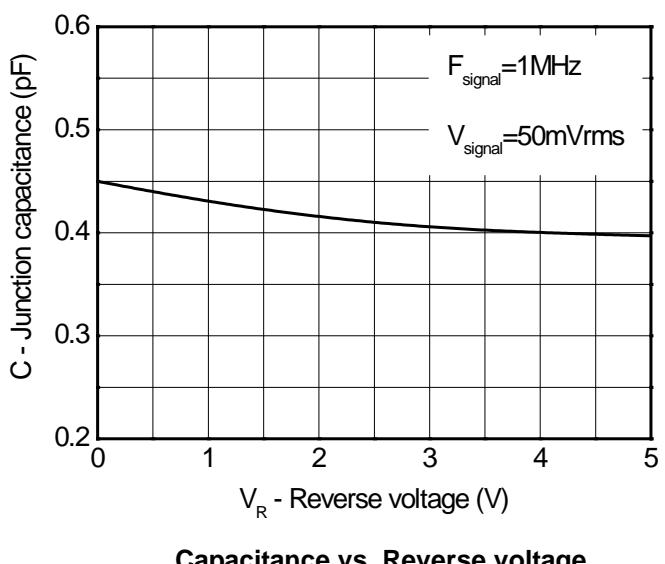
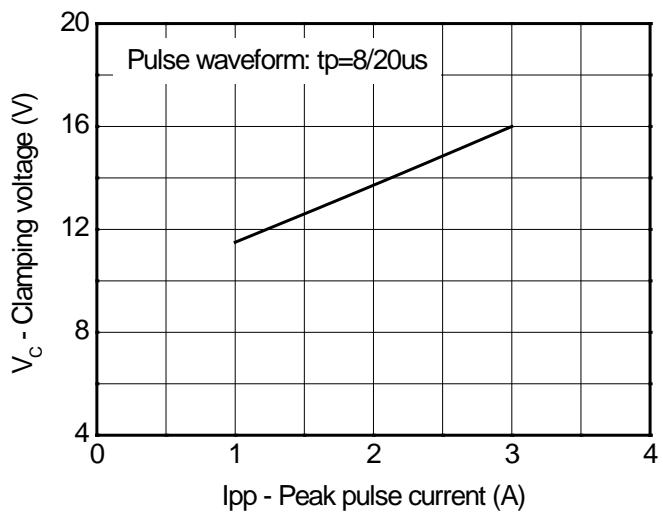
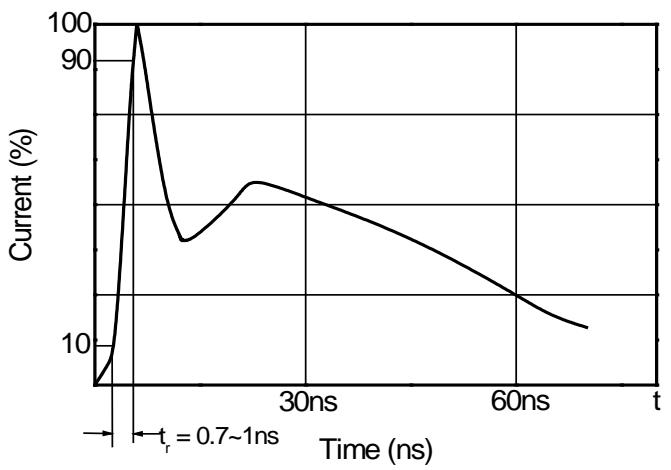
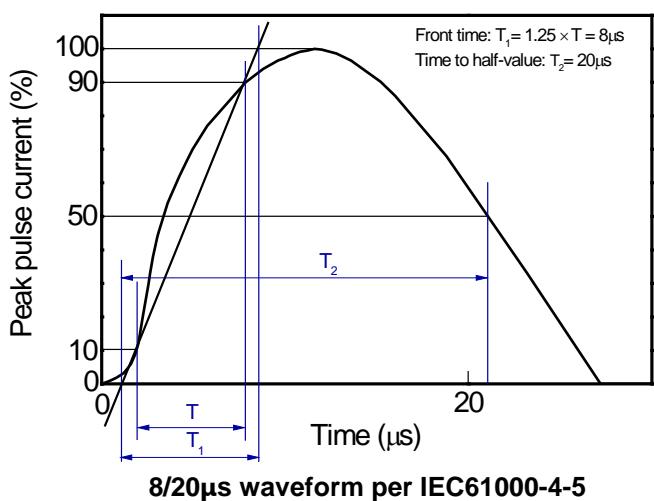
Parameter	Symbol	Rating	Unit
Peak pulse power ( $t_p=8/20\mu s$ )	Ppk	54	W
Peak pulse current ( $t_p=8/20\mu s$ )	Ipp	3	A
ESD voltage IEC61000-4-2 air	$V_{ESD}$	$\pm 15$	KV
ESD voltage IEC61000-4-2 contact		$\pm 12$	
Junction temperature	$T_J$	125	$^{\circ}C$
Operating temperature	$T_{OP}$	-40~85	$^{\circ}C$
Lead temperature	$T_L$	260	$^{\circ}C$
Storage temperature	Tsg	-55~150	$^{\circ}C$

## Electronics characteristics (Ta=25 $^{\circ}C$ , unless otherwise noted)

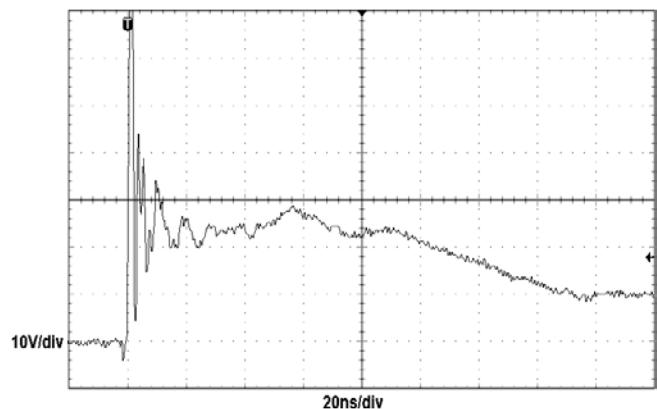
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	$V_{RWM}$				$\pm 5.0$	V
Reveres leakage current	$I_R$	$V_{RWM} = 5V$			1.0	$\mu A$
Reveres breakdown voltage	$V_{BR}$	$I_T = 1mA$	7.0	8.5	10.0	V
Clamping voltage <sup>1)</sup>	$V_{CL}$	$I_{PP} = 16A, t_p = 100ns$		35		V
Dynamic resistance <sup>1)</sup>	$R_{DYN}$			1.61		$\Omega$
Clamping voltage <sup>2)</sup>	$V_{CL}$	$V_{ESD} = 6kV$		27		V
Clamping voltage <sup>2)</sup>	$V_{CL}$	$V_{ESD} = 8kV$		35		V
Clamping voltage <sup>3)</sup>	$V_C$	$Ipp=1A tp=8/20us$		11.8	14	V
		$Ipp=3A tp=8/20us$		16	18	V
Junction capacitance	$C_J$	$F=1MHz, V_R=0V$		0.45	0.7	pF

Notes:

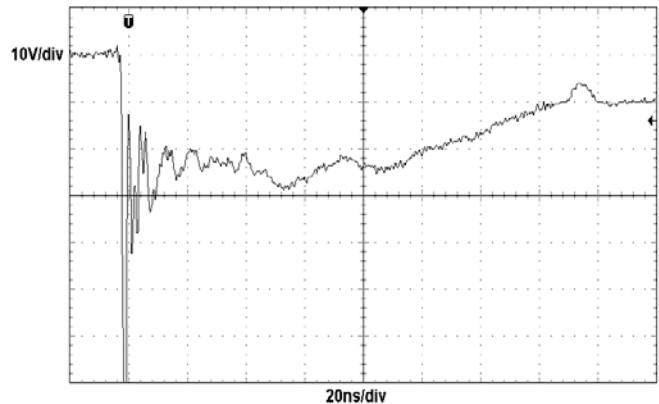
- 1) TLP parameter:  $Z_0 = 50\Omega$ ,  $t_p = 100ns$ ,  $t_r = 2ns$ , averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A.
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.

**Typical characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)**


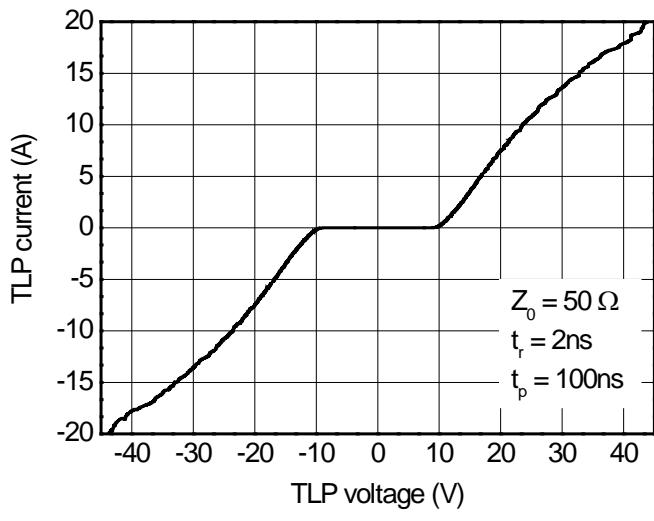
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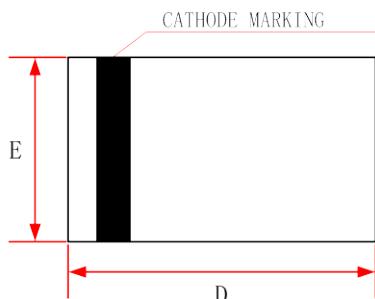
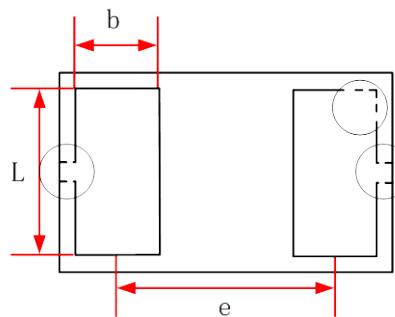
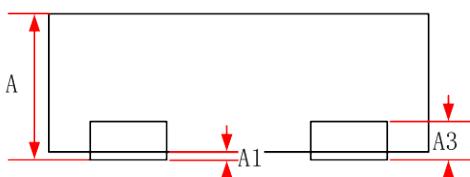
**ESD clamping**  
(+8kV contact discharge per IEC61000-4-2)



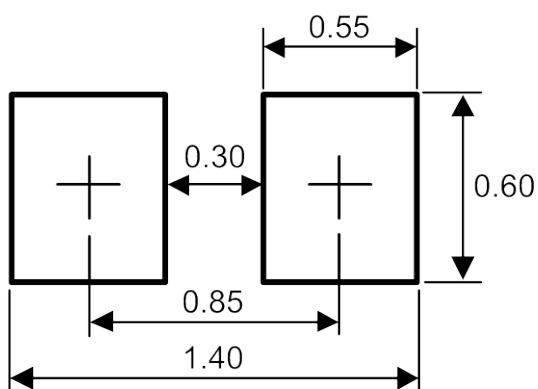
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**TLP Measurement**

**Package outline dimensions**
**DFN1006-2L**

**Top View**

**Bottom View**

**Side View**


	Min.	Typ.	Max.
A	0.30	-	0.50
A1	0.00	-	0.05
A3			0.125 Ref.
D	0.95	1.00	1.05
E	0.55	0.60	0.65
b	0.20	0.25	0.30
L	0.45	0.50	0.55
e	0.65 Typ.		

**Recommend land pattern (Unit: mm)**

**Notes:**

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.